

Type	Hits	Search Text	DBs	Time Stamp
1	BRS 7	((micron.as.) and ((2f54) with (cell or size or area)) and (2000.ay.)	USPAT; US-PGPUB	2002/12/04
2	BRS 7	((micron.as.) and ((2f.sup.2") with (cell or size or area)) and (2000.ay.)	USPAT; US-PGPUB	2002/12/04
3	BRS 19	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/04
4	BRS 1	"20020127798"	USPAT; US-PGPUB	2002/12/04
5	BRS 1	6043562.pn.	USPAT; US-PGPUB	2002/12/04
6	BRS 2	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/04
7	BRS 18	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/04
8	BRS 10	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/04
9	BRS 5	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/04
10	BRS 7	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) with spa	USPAT; US-PGPUB	2002/12/04
11	BRS 9	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/04
12	BRS 23	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/04
13	BRS 2	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/04
14	BRS 14	(US-5874760-\$ or US-5998261-\$ or US-6118159-\$ or US-5495441-\$ or US-5414287-\$ or US-6255689-\$ or US-5	USPAT; US-PGPUB	2002/12/04
15	BRS 9	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
16	BRS 14	(US-6255689-\$ or US-5739567-\$ or US-5828602-\$ or US-5874760-\$ or US-5071782-\$ or US-5576567-\$ or US-5	USPAT; US-PGPUB	2002/12/06
17	BRS 4	((US-6255689-\$ or US-5739567-\$ or US-5828602-\$ or US-5874760-\$ or US-5071782-\$ or US-5576567-\$ or US-	USPAT; US-PGPUB	2002/12/06
18	BRS 11	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
19	BRS 1	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
20	BRS 16	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/06
21	BRS 20	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
22	BRS 0	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	EPO; JPO; DERWENT; IBM_TDB	2002/12/06
23	BRS 30	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
24	BRS 8	"5990509"	USPAT	2002/12/06
25	BRS 11	"5998261"	USPAT; US-PGPUB	2002/12/06
26	BRS 12	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
27	BRS 1	5998261.pn. and (source or drain)	USPAT; US-PGPUB	2002/12/06
28	BRS 9	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
29	BRS 11	((vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
30	BRS 24	"5049956"	USPAT; US-PGPUB	2002/12/06
31	BRS 0	"5049956" and ("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4P\$1square or "4.5P\$1square)	EPO; JPO; DERWENT; IBM_TDB	2002/12/06
32	BRS 1	"5049956" and ("2f.sup.2" or "2f2" or "2.5f.sup.2" or "2.5f2" or "2P\$1square or "2.5P\$1square)	USPAT; US-PGPUB	2002/12/06
33	BRS 1	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/06
34	BRS 1	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/06
35	BRS 0	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/06
36	BRS 0	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/06
37	BRS 1	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/06
38	BRS 1	((floating adj (gate or electrode)) with spacer) and ((conductive or poly\$1si or polysilicon or poly\$1silicon) adj spac	USPAT; US-PGPUB	2002/12/06
39	BRS 5	(vertical with (split\$1gate or (split adj gate))) and (vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fe	USPAT; US-PGPUB	2002/12/06
40	BRS 19	((control or select adj (gate or electrode)) with (trench or groove)) and (vertical with (transistor or fet or mosfet or	USPAT; US-PGPUB	2002/12/06
41	BRS 5	(vertical with (split\$1gate or (split adj gate))) and ((floating adj (gate or electrode))) and ("4f.sup.2" or "4f2" or "4.5f.s	USPAT; US-PGPUB	2002/12/06
42	BRS 4	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
43	BRS 8	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06
44	BRS 8	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/12/06

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43	BRS 8	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/1/2/06
44	BRS 12	((flash or eeprom or eeprom or (non adj volatile) or non\$1volatile).ab.) and (((control or select) adj (gate or electro	USPAT; US-PGPUB	2002/1/2/06
45	BRS 23	(((control or select) adj (gate or electrode)) with (trench or groove)) and ("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f	USPAT; US-PGPUB	2002/1/2/06
46	BRS 17	((((control or select or second) adj (gate or electrode)) with (side\$1wall or (side adj wall))) and ("4f.sup.2" or "4f2" or "4.5f	USPAT; US-PGPUB	2002/1/2/06
47	BRS 8	((((control or select or second) adj (gate or electrode)) with (side\$1wall or (side adj wall))) and ("4f.sup.2" or "4f2" or "4.5f	USPAT; US-PGPUB	2002/1/2/06
48	BRS 26	(((control or select or second) adj (gate or electrode)) with (side\$1wall or (side adj wall))) and ("4f.sup.2" or "4f2" or "4.5f	USPAT; US-PGPUB	2002/1/2/06
49	BRS 7	(((vertical adj channel) or vertical\$1channel) and ("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square or "4	USPAT; US-PGPUB	2002/1/2/06
50	BRS 1	(((vertical adj channel) or vertical\$1channel) and ("2f.sup.2" or "2f2" or "2.5f.sup.2" or "2.5f2" or "2f\$1square or "2	USPAT; US-PGPUB	2002/1/2/06
51	BRS 4	(((vertical adj channel) or vertical\$1channel) and ("f.sup.2" or "f2" or "0.5f.sup.2" or "0.5f2" or "f\$1square or "0.5f	USPAT; US-PGPUB	2002/1/2/06
52	BRS 18	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/1/2/06
53	BRS 21	(vertical with (flash or eeprom or eeprom or (non adj volatile) or non\$1volatile)) and (floating adj (gate or electrode))	USPAT; US-PGPUB	2002/1/2/06
54	BRS 12	(vertical with (flash or eeprom or eeprom or (non adj volatile) or non\$1volatile)) and (floating adj (gate or electrode))	USPAT; US-PGPUB	2002/1/2/06
55	BRS 7	(((vertical adj channel) or (channel adj vertical)) and (floating adj (gate or electrode)) and ("f.sup.2" or "f2" or "0.5f	USPAT; US-PGPUB	2002/1/2/06
56	BRS 7	(("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square or "4.5f\$1square) and ((floating adj (gate or electro	USPAT; US-PGPUB	2002/1/2/06
57	BRS 16	((channel with (perpendicular or orthogonal or orthogonally)) and (floating adj (gate or electrode)) and ("f.sup.2" or "f	USPAT; US-PGPUB	2002/1/2/06
58	BRS 2	(("2f.sup.2" or "2f2" or "2.5f.sup.2" or "2.5f2" or "2f\$1square or "2.5f\$1square) and (channel with (perpendicular	USPAT; US-PGPUB	2002/1/2/06
59	BRS 1	"6008089".PN.	USPAT	2002/1/2/06
60	BRS 1	"6040210".PN.	USPAT	2002/1/2/06
61	BRS 8	"6008089"	USPAT; US-PGPUB	2002/1/2/06
62	BRS 26	((((control or select or second) adj (gate or electrode)) with vertical) and ("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f	USPAT; US-PGPUB	2002/1/2/06
63	BRS 0	(("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square or "4.5f\$1square) and (floating adj (gate or electro	USPAT; US-PGPUB	2002/1/2/06
64	BRS 15	((((control or select or second) adj (gate or electrode)) with (trench or groove)) and ("4f.sup.2" or "4f2" or "4.5f	USPAT; US-PGPUB	2002/1/2/06
65	BRS 1	"4868628".PN.	USPAT	2002/1/2/06
66	BRS 1	"4914740".PN.	USPAT	2002/1/2/06
67	BRS 1	"5040036".PN.	USPAT	2002/1/2/06
68	BRS 1	"5051795".PN.	USPAT	2002/1/2/06
69	BRS 1	"5115288".PN.	USPAT	2002/1/2/06
70	BRS 1	"5331189".PN.	USPAT	2002/1/2/06
71	BRS 1	"5338953".PN.	USPAT	2002/1/2/06
72	BRS 1	"4796228".PN.	USPAT	2002/1/2/06
73	BRS 1	"4868619".PN.	USPAT	2002/1/2/06
74	BRS 1	"4929988".PN.	USPAT	2002/1/2/06
75	BRS 1	"4972371".PN.	USPAT	2002/1/2/06
76	BRS 1	"5045490".PN.	USPAT	2002/1/2/06
77	BRS 1	"5180680".PN.	USPAT	2002/1/2/06
78	BRS 1	"4975384".PN.	USPAT	2002/1/2/06
79	BRS 1	"5045490".PN.	USPAT	2002/1/2/06
80	BRS 1	"5049515".PN.	USPAT	2002/1/2/06
81	BRS 1	"4222062".PN.	USPAT	2002/1/2/06
82	BRS 1	"3825945".PN.	USPAT	2002/1/2/06
83	BRS 1	"3975221".PN.	USPAT	2002/1/2/06
84	BRS 1	"3992701".PN.	USPAT	2002/1/2/06
85	BRS 1	"4713677".PN.	USPAT	2002/1/2/06
86	BRS 1	"4713677".PN.	USPAT	2002/1/2/06

Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Defined	Errors
43	BRS 8	(vertical with (transistor or fet or mosfet or misfet or fet or mos\$1fet or mis\$1fet or igfet or ig\$1fet or metal\$1oxide	USPAT; US-PGPUB	2002/1/2/06			

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85	BRS 1	"4713677".PN.	USPAT	2002/12/06
86	BRS 1	"4786228".PN.	USPAT	2002/12/06
87	BRS 1	"4814840".PN.	USPAT	2002/12/06
88	BRS 1	"4814840".PN.	USPAT	2002/12/06
89	BRS 1	"4786228".PN.	USPAT	2002/12/06
90	BRS 1	"4868618".PN.	USPAT	2002/12/06
91	BRS 1	"4929988".PN.	USPAT	2002/12/06
92	BRS 1	"4972371".PN.	USPAT	2002/12/06
93	BRS 1	"5045490".PN.	USPAT	2002/12/06
94	BRS 1	"5180680".PN.	USPAT	2002/12/06
95	BRS 13	((control or select or second) adj (gate or electrode)) with (trench or groove)) and (((floating adj (gate or electro	USPAT; US-PGPUB	2002/12/06
96	BRS 1	"5049515".PN.	USPAT	2002/12/06
97	BRS 1	"5071782".PN.	USPAT	2002/12/06
98	BRS 1	"5135879".PN.	USPAT	2002/12/06
99	BRS 1	"5045490".PN.	USPAT	2002/12/06
100	BRS 1	"5049515".PN.	USPAT	2002/12/06
101	BRS 1	"5162247".PN.	USPAT	2002/12/06
102	BRS 1	"5180680".PN.	USPAT	2002/12/06
103	BRS 1	"5313421".PN.	USPAT	2002/12/06
104	BRS 1	"5460989".PN.	USPAT	2002/12/06
105	BRS 1	"5467305".PN.	USPAT	2002/12/06
106	BRS 1	"5468663".PN.	USPAT	2002/12/06
107	BRS 1	"5595927".PN.	USPAT	2002/12/06
108	BRS 1	"5786612".PN.	USPAT	2002/12/06
109	BRS 1	"5242848".PN.	USPAT	2002/12/06
110	BRS 1	"5049515".PN.	USPAT	2002/12/06
111	BRS 1	"5488244".PN.	USPAT	2002/12/06
112	BRS 1	"5495441".PN.	USPAT	2002/12/06
113	BRS 6	(floating adj (gate or electrode)) and (("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square or "4.5f\$1squ	USPAT; US-PGPUB	2002/12/06
114	BRS 7	("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square or "4.5f\$1square) and (channel with (perpendicular	USPAT; US-PGPUB	2002/12/06
115	BRS 27	(floating adj (gate or electrode)) and ("5495441") and (cell with (size or area))	USPAT; US-PGPUB	2002/12/06
116	BRS 1	"6316315".PN.	USPAT; US-PGPUB	2002/12/06
117	BRS 1	"5049515".PN.	USPAT	2002/12/06
118	BRS 1	"5242848".PN.	USPAT	2002/12/06
119	BRS 1	"5488244".PN.	USPAT	2002/12/06
120	BRS 1	"5442214".PN.	USPAT	2002/12/06
121	BRS 1	"5495441".PN.	USPAT	2002/12/06
122	BRS 24	("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square or "4.5f\$1square) and ("5495441")	USPAT; US-PGPUB	2002/12/06
123	BRS 1	"4970689".PN.	USPAT	2002/12/06
124	BRS 1	"5291439".PN.	USPAT	2002/12/06
125	BRS 1	"5313421".PN.	USPAT	2002/12/06
126	BRS 1	"5343063".PN.	USPAT	2002/12/06
127	BRS 1	"4075383".PN.	USPAT	2002/12/06

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124	BRS 1	"5291439".PN.	USPAT	2002/12/06
125	BRS 1	"5313421".PN.	USPAT	2002/12/06
126	BRS 1	"5343063".PN.	USPAT	2002/12/06
127	BRS 1	"4975383".PN.	USPAT	2002/12/06
128	BRS 1	"5304503".PN.	USPAT	2002/12/06
129	BRS 1	"5141886".PN.	USPAT	2002/12/06
130	BRS 1	"5135879".PN.	USPAT	2002/12/06
131	BRS 14	("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square" or "4.5f\$1square") and ((hofmann and franz).in.)	USPAT; US-PGPUB	2002/12/06
132	BRS 5	("2f.sup.2" or "2f2" or "2.5f.sup.2" or "2.5f2" or "2f\$1square" or "2.5f\$1square") and ((floating adj (gate or electro	USPAT; US-PGPUB	2002/12/06
133	BRS 23	"4975383"	USPAT; US-PGPUB	2002/12/06
134	BRS 1	"5071782".PN.	USPAT	2002/12/06
135	BRS 1	"5049515".PN.	USPAT	2002/12/06
136	BRS 1	"5045490".PN.	USPAT	2002/12/06
137	BRS 1	"4975383".PN.	USPAT	2002/12/06
138	BRS 22	"5141886"	USPAT; US-PGPUB	2002/12/06
139	BRS 0	("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square" or "4.5f\$1square") and "5141886"	USPAT; US-PGPUB	2002/12/06
140	BRS 0	("2f.sup.2" or "2f2" or "2.5f.sup.2" or "2.5f2" or "2f\$1square" or "2.5f\$1square") and "5141886"	USPAT; US-PGPUB	2002/12/06
141	BRS 0	("2f.sup.2" or "2f2" or "2.5f.sup.2" or "2.5f2" or "2f\$1square" or "2.5f\$1square") and "5135879"	USPAT; US-PGPUB	2002/12/06
142	BRS 1	"5045490".PN.	USPAT	2002/12/06
143	BRS 1	"5135879".PN.	USPAT	2002/12/06
144	BRS 1	"5180680".PN.	USPAT	2002/12/06
145	BRS 1	"5278438".PN.	USPAT	2002/12/06
146	BRS 1	"5278438".PN.	USPAT	2002/12/06
147	BRS 19	"5135879"	USPAT	2002/12/06
148	BRS 16	"5973352"	USPAT; US-PGPUB	2002/12/06
149	BRS 0	("4f.sup.2" or "4f2" or "4.5f.sup.2" or "4.5f2" or "4f\$1square" or "4.5f\$1square") and "5135879"	USPAT; US-PGPUB	2002/12/06
150	BRS 1	5998281.pn. and (selector)	USPAT; US-PGPUB	2002/12/06
151	BRS 1	"20020127798" and (select adj transistor)	USPAT; US-PGPUB	2002/12/06
152	BRS 1	"20020127798" and (self\$1align or self\$1aligning or self\$1aligned)	USPAT; US-PGPUB	2002/12/06
153	BRS 9	(digit\$1line) with (floating adj gate)	USPAT; US-PGPUB	2002/12/06
154	BRS 1	"20020127798" and (digit\$1line or (digit adj line))	USPAT; US-PGPUB	2002/12/06
155	BRS 3	(hofmann and franz).in. and (((floating adj gate) with (bit\$1line or (bit adj line))))	USPAT; US-PGPUB	2002/12/06
156	BRS 0	"20020127798" and (bit\$1line or (bit adj line))	USPAT; US-PGPUB	2002/12/06
157	BRS 1	"20020127798"	USPAT; US-PGPUB	2002/12/06
158	BRS 1	"20020127798"	USPAT; US-PGPUB	2002/12/06
159	BRS 0	"20020127798" and (correspond or corresponding)	USPAT; US-PGPUB	2002/12/06
160	BRS 0	"20020127798" and corresponding	USPAT; US-PGPUB	2002/12/06
161	BRS 0	20020127798.pn. and corresponding	USPAT; US-PGPUB	2002/12/06
162	BRS 1	20020127798.pn.	USPAT; US-PGPUB	2002/12/06
163	BRS 1	"20020127798" and (minimum)	USPAT; US-PGPUB	2002/12/06
164	BRS 1	"20020127798" and (boron)	USPAT; US-PGPUB	2002/12/06
165	BRS 1	"20020127798" and (doped or doping or dopant)	USPAT; US-PGPUB	2002/12/06

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Ready							